

PNP HIGH POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/379

Devices Qualified Level

2N3791 2N3792

JAN JANTX JANTXV

MAXIMUM RATINGS

WAZIWIOW KATINOS					
Ratings	Symbol	2N3791	2N3792	Unit	
Collector-Emitter Voltage	V_{CEO}	60	80	Vdc	
Collector-Base Voltage	V_{CBO}	60	80	Vdc	
Emitter-Base Voltage	V_{EBO}	7.0		Vdc	
Base Current	I_{B}	4.0		Adc	
Collector Current	I_{C}	10		Adc	
Total Power Dissipation @ $T_A = +25^0 C^{(1)}$		5.0		W	
@ $T_C = +100^0 C^{(2)}$	P_{T}	85	5.7	W	
Operating & Storage Junction Temperature Range	T _J , T _{stg}	-65 to	+200	°C	

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	1.17	⁰ C/W

- 1) Derate linearly @ $28.57 \text{ mW/}^{\circ}\text{C}$ for $T_A > +25^{\circ}\text{C}$
- 2) Derate linearly @ $0.857 \text{ mW}/{}^{0}\text{C}$ for $T_{C} > +100{}^{0}\text{C}$



*See Appendix A for Package Outline

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}$ C unless otherwise noted)

Characteris	tics	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage					
$I_C = 10 \text{ mAdc}$	2N3791	$V_{(BR)CEO}$	60		Vdc
	2N3792		80		
Collector-Emitter Cutoff Current					
$V_{CE} = 50 \text{ Vdc}$	2N3791	I_{CES}		5.0	mAdc
$V_{CE} = 70 \text{ Vdc}$	2N3792			5.0	
Collector-Emitter Cutoff Current					
$V_{CE} = 60 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$	2N3791	I_{CEX}		5.0	mAdc
$V_{CE} = 80 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$	2N3792			5.0	

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2N3791, 2N3792 JAN SERIES

ELECTRICAL CHARACTERISTICS (con't)

Characteristics		Symbol	Min.	Max.	Unit
Collector-Base Cutoff Current					
$V_{CB} = 60 \text{ Vdc}$	2N3791	I_{CBO}		5.0	mAdc
$V_{CB} = 80 \text{ Vdc}$	2N3792			5.0	
Emitter-Base Cutoff Current					
$V_{EB} = 7.0 \text{ Vdc}$		I_{EBO}		5.0	mAdc
ON CHARACTERISTICS (3)					
Forward-Current Transfer Ratio					
$I_C = 1.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$			50	150	
$I_C = 3.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$		$h_{ m FE}$	30	120	
$I_C = 5.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$			10		
$I_C = 10 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$			5.0		
Collector-Emitter Saturation Voltage					
$I_C = 5.0 \text{ Adc}, I_B = 0.5 \text{ Adc}$		V _{CE(sat)}		1.0	Vdc
$I_{\rm C} = 10 \text{ Adc}, I_{\rm B} = 2.0 \text{ Adc}$				2.5	
Base-Emitter Saturation Voltage					
$I_C = 5.0 \text{ Adc}, I_B = 0.5 \text{ Adc}$		V _{BE(sat)}		1.5	Vdc
$I_C = 10 \text{ Adc}, I_B = 2.0 \text{ Adc}$				3.0	
DYNAMIC CHARACTERISTICS					
Magnitude of Common Emitter Small-Signal	Short-Circuit				
Forward Current Transfer Ratio					
$I_C = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ MHz}$		$ h_{\mathrm{fe}} $	4.0	20	
Small-Signal Short-Circuit Forward Current	Γransfer Ratio				
$I_C = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$		h_{fe}	30	300	
Output Capacitance					
$V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$		C_{obo}		500	pF

SAFE OPERATING AREA

DC Tests

 $T_C = +25^{\circ}C$, 1 Cycle, $t \ge 1.0 \text{ s}$

Test 1

 $V_{CE} = 15 \text{ Vdc}, I_C = 10 \text{ Adc}$

Test 2

 $V_{CE} = 40 \text{ Vdc}, I_C = 3.75 \text{ Adc}$

Test 3

 $V_{CE} = 55 \text{ Vdc}, I_C = 0.9 \text{ Adc}$ 2N3791 $V_{CE} = 65 \text{ Vdc}, I_C = 0.9 \text{ Adc}$ 2N3792

(3) Pulse Test: Pulse Width = $300\mu s$, Duty Cycle $\leq 2.0\%$.

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